

Solid State High Power Amplifier

2232

5200 - 5900 MHz / 2.5 kW_{PK} Pulsed

The 2232 is a single drawer unit that produces a minimum output of 2.5 kW peak pulsed power and 500W CW power. The amplifier features multiple high power GaN on SiC devices that provide wide frequency response, high gain, high peak power capability, and low distortions. Exceptional performance, long-term reliability and high efficiency are achieved by employing advanced broadband RF matching networks and combining techniques, EMI/RFI filters, and all qualified components. The amplifier includes integral forced air-cooling fans. Available operating voltage configurations are single phase, three phase AC up to 400 hertz and 28 volts DC



The amplifier includes a built-in control and monitoring system, with protection functions which preserve maximum output capability and reliability. Remote management and diagnostics are via an embedded web server allowing network managed site status and control simply by connecting the unit's Ethernet port to a LAN. Using a web browser and the unit's IP address (IPV4) allows ease of access with the benefit of multilevel security. The control system core supports hardware encryption, runs an embedded OS (Linux), has a built-in non-volatile memory for event recording, and factory setup recovery features. The extended memory option allows storage of control parameters and event logs.

We are delivering more than just RF power, the next generation family of systems provide dynamic adjustments linked to the processing power and digital controls, which focus on maximizing system availability time as well as power output under ALL conditions.

Empower RF's ISO9001:2015 Quality Assurance Program assures consistent performance and the highest reliability.

- Solid-state class AB design
- Suitable for instantaneous pulse operation over the operating band.
- Compact Modular design and scalable architecture
- 50 ohm input/output impedance
- Built-in Control, Monitoring and Protection functions
- High reliability and ruggedness

ELECTRICAL SPECIFICATIONS over temperature conditions (0 to +50°C)

ELECTRICAL SPECIFICATIONS Over temperature conditions (0 to 750°C)						
Para	meter	Symbol	Min	Typical	Max	Unit
Operating Frequency		BW	5200		5900	MHz
Power Output - Peak Puls	se	P _{SAT_PK}	2500			Watt
Power Output – CW		P _{SAT_CW}	500			Watt
Pulse Width @ Duty Cycle	20% _(NOTE)	P _{WIDTH}	1		500	μSec
Duty Cycle			0.5		20	%
Pulse Repetition Rate Free	quency	PRF	0.5		25	kHz
Power Gain @ Rated Pea	k P _{OUT} - Pulse	G _{PK}	65			dB
Pulse Droop @ 500µSec Pulse Width		P _{DROOP}		1.2	1.5	dB
Modulated Pulse Rise/Fall Time (10% to 90%)		T _{RISE} /T _{FALL}		70/70	150/150	nSec
Input power for rated Output – Pulse & CW signal		P _{IN}		-5	0	dBm
Input Return Loss		S ₁₁			-10	dB
NPO – Noise Power Output		Enabled			-10	dBm/MHz
		Disabled			-106	UDITI/IVITIZ
Harmonics @ P _{OUT_PULSE} = 2.5kW _{PK}		2 ND -5 TH		-40		dBc
Spurious Signals		Spur			-60	dBc
Operating Voltage	3-phase (Line-to-Line)	V _{AC}	180	208	260	Volt
	1-Phase		100		260	
Power Consumption @ 20% _{DC} , P _{OUT_PULSE} = 2.5W _{PK}		P _D		1350	1750	VA

NOTE: Call factory for application >20% duty cycle.

PROTECTIONS

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Parameter	Specification	Unit
Input Overdrive	≥10 dBm – Shutdown	-
Load VSWR Protection	The unit disables the RF when reverse power exceeds the safe level @ all load phase & amplitude	-
Thermal Shutdown	Baseplate ≥90 °C	-
Default Data Recovery	Factory Default Calibration Recovery	-



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MECHANICAL SPECIFICATIONS

Parameter	Value	Unit
Overall Dimension (W x H x D) (excludes handles, connectors and brackets)	17.5 x 8.75 x 22.0	Inch
Total Weight	95	Pound
RF Connectors Input/Output	Input: N-Type, Female	RF IN
INF Connectors input/Output	Output: 7/16-DIN, Female	RF OUT
RF Sample Connectors	Type-SMA, Female	Forward / Reverse
Blanking/Gating Input Connector	BNC Female	Blanking
Cooling	Built-in forced-air system – Front-to-Rear	Airflow Direction

ENVIRONMENTAL CHARACTERISTICS:

Parameter	Symbol	Min	Тур	Max	Unit
Operating Ambient Temperature NOTE 1	T _C	-10		+50	Ĵ
Non-operating Temperature	T _{STG}	-35		+75	Ĵ
Relative humidity (non-condensing)	RH			95	%
Altitude (MIL-STD-810F)	ALT			10,000	Feet
Shock / Vibration (MIL-STD-810F,	SH / VI				
Shock Method 516.5, Vibration Method 514.5)	SH / VI				-

Note: 1. Call factory for extended operating temperature range.

COMMUNICATION INTERFACES:

Function	Utility	Connector	
Ethernet	Network management of device / web interface	RJ45	
USB	Mass Storage / Expansion Bus	USB 1.x/2.0 compatible	
RS-232, Standard (RS-422, factory configurable)	Serial management device / local operator access	D-sub, 9-position Male	

SYSTEM I/O CONNECTOR - 14-Position

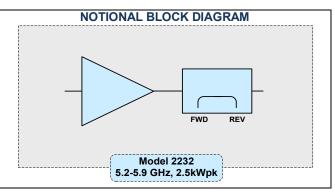
Pin#	Description	Specification
1	FWD Test Point	Forward detected power (analog voltage: 0-5 Volt)
2	REV Test Point	Reverse detected power (analog voltage: 0-5 Volt)
3	Summary Fault	Summary Fault: Active TTL Logic Low (≤0.7V)
		(Internally Pulled-High)
4	N/C	No Connection (reserved)
5	Shutdown	Amplifier Disable: TTL Logic Low (≤0.7V)
3		(Internally Pulled-High)
6	Aux P/S Test Point	+12.0V _{DC} ±2.0V (resettable 0.5amp fuse)
7	Main P/S Test Point	+44.0V _{DC} ±4.8V (resettable 0.5amp fuse)
8	GND	Ground
9-11	Open drain control	Site management utility (reserved)
12&13	Digital I/O (configurable)	Site management utility (reserved)
14	GND	Ground

Available Options

2232-00X
-001 180-260 VAC, 3-phase-Delta, 47-63 Hz, Rear RF Connectors
-002 TBD
Contact us for other available options; sales@empowerrf.com

Standard Feature:

- -LCD Control, Ethernet & Serial Comm
- -Sample Port: SMA-F [Forward & Reverse]
- -Blanking/Gating Port: BNC-F
- -Rack Slides, Handles and Rackmount Brackets





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